

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Original) An electro-optical device, comprising:

first electrodes on a base body;

a plurality of element areas including element layers having at least one functional layer disposed above the first electrodes;

a second electrode formed above the element layers;

surrounding sections disposed on the base body so as to cover outer sides of the element layers including the element areas in a nearest proximity of a periphery of the base body; and

a gas-barrier layer that covers the second electrode, outer sides of the surrounding sections being covered with the second electrode, and the gas-barrier layer being in contact with the base body.

- 2. (Currently Amended) A method for manufacturing the An electro-optical device according to claim 1, wherein the element layers functioning by carriers supplied from the first electrodes or the second electrode and passing through the element layers.
- 3. (Original) An electro-optical device according to claim 1, the gas-barrier layer comprising an inorganic compound.
- 4. (Original) An electro-optical device according to claim 1, the gas-barrier layer comprising a silicon compound.
- 5. (Original) An electro-optical device according to claim 3, at least a face that is in contact with the gas-barrier layer of the second electrode comprising an inorganic oxide.
- 6. (Original) An electro-optical device according to claim 1, an angle defined by outer faces of the surrounding sections and the base body being 110° or more.

- 7. (Original) An electro-optical device according to claim 1, the electro-optical device being an active matrix electro-optical device.
- 8. (Original) An electro-optical device according to claim 1, the gas-barrier layer having an oxygen concentration which is lower at a face adjacent to the second electrode than at an upper face.
- 9. (Original) An electro-optical device according to claim 1, further comprising a protective layer that covers the gas-barrier layer on the gas-barrier layer.
- 10. (Original) An electro-optical device according to claim 9, the protective layer comprising a surface-protective sublayer on a surface of the protective layer.
- 11. (Original) An electro-optical device according to claim 9, the protective layer comprising a buffer sublayer that adheres to the gas-barrier layer and has a buffer function against mechanical shock on a gas-barrier layer side.
- 12. (Original) An electro-optical device according to claim 11, the buffer sublayer comprising a silane coupling agent or alkoxysilane.

13.	(Currently Amended) An electronic apparatus comprises the comprising an
electro-optic	al device according to claim 1. that comprises:
	first electrodes on a base body;
	a plurality of element areas including element layers having at least one
functional la	yer disposed above the first electrodes;
	a second electrode formed above the element layers;
	surrounding sections disposed on the base body so as to cover outer sides of
the element l	ayers including the element areas in a nearest proximity of a periphery of the
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a gas-barrier layer that covers the second electrode, outer sides of the surrounding sections being covered with the second electrode, and the gas-barrier layer being in contact with the base body.